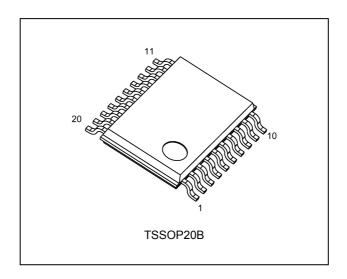
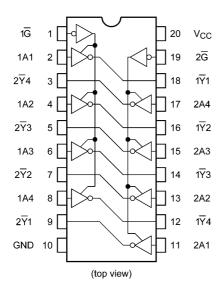


### 4. Packaging

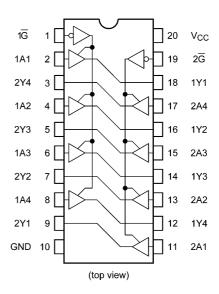


### 5. Pin Assignment

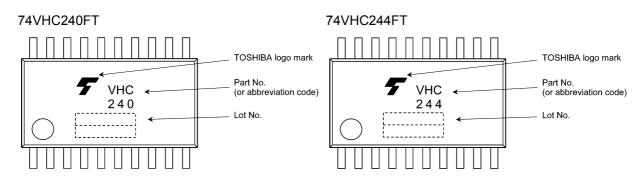
74VHC240FT



#### 74VHC244FT



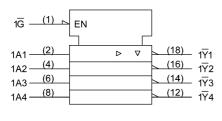
### 6. Marking

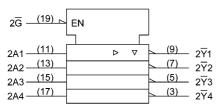




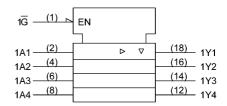
### 7. IEC Logic Symbol

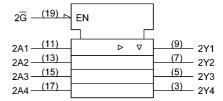
#### 74VHC240FT





#### 74VHC244FT





#### 8. Truth Table

Input G	Input A <sub>n</sub>	Output Y <sub>n</sub>	Output $\overline{Y}_n$
L	L	L	Н
L	ь н н		L
Н	Х	Z	Z

 $\begin{array}{lll} \text{X:} & \text{Don't care} \\ \text{Z:} & \text{High impedance} \\ \text{Y}_{\text{n}}\text{:} & \text{74VHC244FT} \\ \hline{\text{Y}}_{\text{n}}\text{:} & \text{74VHC240FT} \\ \end{array}$ 

#### 9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Output voltage	V <sub>out</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	lok		±20	mA
Output current	l <sub>out</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	$P_D$	(Note 1)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.



# 10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		2.0 to 5.5	V
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Output voltage	V <sub>OUT</sub>		0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv	$V_{CC}$ = 3.3 ± 0.3 V	0 to 100	ns/V
		V <sub>CC</sub> = 5 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

### 11. Electrical Characteristics

# 11.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	_	V
				3.0 to 5.5	V <sub>CC</sub> × 0.7	_	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	_	0.50	V
				3.0 to 5.5	_	_	$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I <sub>OH</sub> = -4 mA	3.0	2.58	_	_	
			I <sub>OH</sub> = -8 mA	4.5	3.94	_	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	_	0.36	
			$I_{OL}$ = 8 mA	4.5	_	_	0.36	
3-state output OFF-state leakage current	l <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.25	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	μΑ
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	μΑ



# 11.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				3.0 to 5.5	V <sub>CC</sub> × 0.7	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	0.50	V
				3.0 to 5.5	_	V <sub>CC</sub> × 0.3	]
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	1 I
				4.5	4.4	_	1
			I <sub>OH</sub> = -4 mA	3.0	2.48	_	
			I <sub>OH</sub> = -8 mA	4.5	3.80	_	1 I
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	1 I
			I <sub>OL</sub> = 4 mA	3.0	_	0.44	
			I <sub>OL</sub> = 8 mA	4.5	_	0.44	
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±2.50	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND	_	0 to 5.5		±1.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μА

# 11.3. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 125 °C)

Characteristics	Symbol	Test Condition	on	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				3.0 to 5.5	V <sub>CC</sub> × 0.7	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	0.50	V
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.40	_	
			I <sub>OH</sub> = -8 mA	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	0.55	
			I <sub>OL</sub> = 8 mA	4.5	_	0.55	
3-state output OFF-state leakage current	l <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	±10.0	μА
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5		±2.0	μΑ
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	80.0	μΑ



# 11.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	74VHC240FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	_	5.3	7.5	ns
						50	_	7.8	11.0	
					$5.0 \pm 0.5$	15	_	3.6	5.5	
						50	_	5.1	7.5	
Propagation delay time	74VHC244FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3\pm0.3$	15	_	5.8	8.4	ns
						50	_	8.3	11.9	
					5.0 ± 0.5	15	_	3.9	5.5	
						50	_	5.4	7.5	
3-state output enable time		$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	15	_	6.6	10.6	ns
						50	_	9.1	14.1	
					5.0 ± 0.5	15	_	4.7	7.3	
						50	_	6.2	9.3	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	50	_	10.3	14.0	ns
					5.0 ± 0.5	50	_	6.7	9.2	
Output skew		t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3 \pm 0.3$	50	_	_	1.5	ns
					$5.0 \pm 0.5$	50	_	_	1.0	
Input capacitance		C <sub>IN</sub>					_	4	10	pF
Output capacitance		C <sub>OUT</sub>					_	6	_	pF
Power dissipation	74VHC240FT	C <sub>PD</sub>	(Note 2)	_			_	17	_	pF
capacitance	74VHC244FT						_	19	_	

Note 1: Parameter guaranteed by design. ( $t_{osLH} = |t_{PLH}m - t_{PLH}n|$ ,  $t_{osHL} = |t_{PHL}m - t_{PHL}n|$ )

Note 2:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$  (per bit)

#### 11.5. AC Characteristics

### (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	74VHC240FT	$t_{PLH}, t_{PHL}$		_	$3.3 \pm 0.3$	15	1.0	9.0	ns
						50	1.0	12.5	
					$5.0 \pm 0.5$	15	1.0	6.5	
						50	1.0	8.5	
Propagation delay time	74VHC244FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	1.0	10.0	ns
						50	1.0	13.5	
					5.0 ± 0.5	15	1.0	6.5	
						50	1.0	8.5	
3-state output enable time		$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	15	1.0	12.5	ns
						50	1.0	16.0	
					$5.0 \pm 0.5$	15	1.0	8.5	
						50	1.0	10.5	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	50	1.0	16.0	ns
					$5.0 \pm 0.5$	50	1.0	10.5	
Output skew		t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3 \pm 0.3$	50	1	1.5	ns
					$5.0 \pm 0.5$	50	_	1.0	
Input capacitance		C <sub>IN</sub>		_			1	10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 



# 11.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

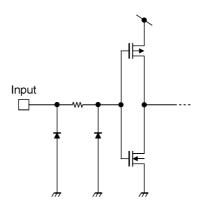
Characteristics	Part Number	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	74VHC240FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	1.0	10.5	ns
						50	1.0	14.0	
					5.0 ± 0.5	15	1.0	7.5	
						50	1.0	9.5	
Propagation delay time	74VHC244FT	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	$3.3 \pm 0.3$	15	1.0	11.5	ns
						50	1.0	15.0	
					$5.0 \pm 0.5$	15	1.0	7.5	
						50	1.0	9.5	
3-state output enable time		$t_{PZL}, t_{PZH}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	15	1.0	14.0	ns
						50	1.0	17.5	
					$5.0 \pm 0.5$	15	1.0	10.0	
						50	1.0	12.0	
3-state output disable time		$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	$3.3 \pm 0.3$	50	1.0	17.5	ns
					$5.0 \pm 0.5$	50	1.0	11.5	
Output skew		t <sub>osLH</sub> ,t <sub>osHL</sub>	(Note 1)	_	$3.3\pm0.3$	50		1.5	ns
					$5.0 \pm 0.5$	50		1.0	
Input capacitance		C <sub>IN</sub>		_			_	10	pF

Note 1: Parameter guaranteed by design.  $(t_{osLH} = |t_{PLH}m-t_{PLH}n|, t_{osHL} = |t_{PHL}m-t_{PHL}n|)$ 

# 11.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_f = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.5	-0.8	V
Minimum high-level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	_	3.5	V
Maximum low-level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0		1.5	V

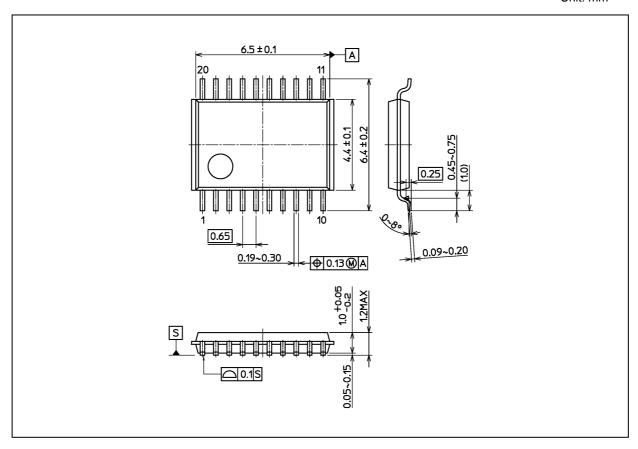
### 11.8. Internal Equivalent Circuit





# **Package Dimensions**

Unit: mm



Weight: 0.071 g (typ.)

	Package Name(s)
Nickname: TSSOP20B	



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